NSN 5962-01-281-6999



Memory Microcircuit - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5962-01-281-6999 **Body Length:** Between 1.130 inches and 1.260 inches **Body Width:** Between 0.475 inches and 0.530 inches **Body Height:** 0.160 inches **Maximum Power Dissipation Rating:** 525.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+125.0 degrees celsius **Features Provided:** Electrostatic sensitive and w/enable and hermetically sealed and ultraviolet erasable and programmable **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Metal oxide-semiconductor logic **Input Circuit Pattern:** 14 input **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 26.5 volts power source **Time Rating Per Chacteristic:** 450.00 nanoseconds propagation delay time, low to high level output and 450.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Rom

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

24 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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